

SANYO Semiconductors DATA SHEET

Bi-CMOS LSI

LV8082LP—

Two Constant-current H-Bridge Driver channels

Overview

The LV8082LP is a two-channel constant-current driver that supports low-voltage operation. It is optimal for constant-current drive of stepping motors (AF and Shutter) in portable equipment such as camera cell phones.

Features

- Two constant-current H-bridge driver channels
- Built-in power supply switch and position detection comparator for use with a photoreflector
- Supports both 2-phase drive and 1-2 phase drive.
- Implemented in a low-power MOS IC process.
- Ultraminiature easy to solder VCT16 package (2.6 × 2.6mm)
- Built-in thermal protection and low-voltage sensing circuits

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Unit	
Maximum supply voltage	V _{CC} , VM max		6.5	V
Output voltage	V _{OUT} max	OUT1, OUT2, OUT3, OUT4	6.5	V
Input voltage	V _{IN} max	IN	-0.3 to +6.5	V
Ground pin source current	IGND	Per channel	400	mA
Allowable power dissipation	Pd max	Mounted on a circuit board.*	700	mW
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-40 to +150	°C

^{*} Specified circuit board : 50×40×0.8mm³ : 4-layer (2S2P) glass epoxy printed circuit board

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LV8082LP

Allowable Operating Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	Vcc		2.5 to 6.0	V
High-level input voltage	VIH	IN	0.53V _{CC} or more	V
Low-level input voltage	V _{IL}		Up to 0.2V _{CC}	V

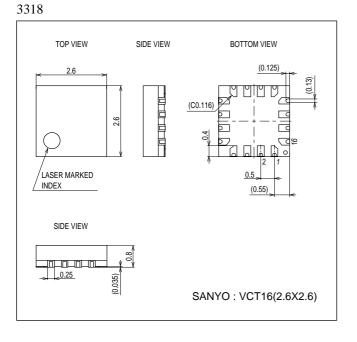
Electrical Characteristics at Ta = 25°C, $V_{CC} = 3.0$ V

D	O. made at	0 - 111	Ratings			11.7	
Parameter	Symbol	Conditions	min	min typ max		Unit	
Current drain	Icco	IN = 0V		0.1	1	μΑ	
	Icco1	IN = 3V		0.7	1	mA	
Output on resistance	Ron1	V _{CC} = 3.0V (High and low side total) IN = 3.0V, I _{OUT} = 100mA		2.0	3.0	Ω	
	Ron2	V _{CC} = 5.0V (High and low side total) IN = 5.0V, I _{OUT} = 100mA		1.50	2.0	Ω	
Constant-voltage output 1	V _{OUT} 1	VC = 1V, V _{CC} = 3.0V	1.94	2.0	2.06	V	
Constant-current output 1	I _{OUT} 1	Between RFG and ground : 1Ω	95	100	105	mA	
Constant-current output 2	l _{OUT} 2	Between RFG and ground : 0.5Ω (Design specification)	190	200	210	mA	
Output turn-on time	Traise	With RFG1 and RFG2 shorted to ground (Design specification)		1.5	3	μS	
Output turn-off time	Tfall	With RFG1 and RFG2 shorted to ground (Design specification)	0.2		0.65	μS	
Comparator threshold high-level voltage	VH			1.3	1.37	V	
Comparator threshold Low-level voltage	VL		0.86	0.91		V	
Comparator hysteresis	Vhys			0.39		V	
Input current	I _{IN}	V _{IN} = 3V		15	30	μА	

Note: The design specification items are design guarantees and are not measured.

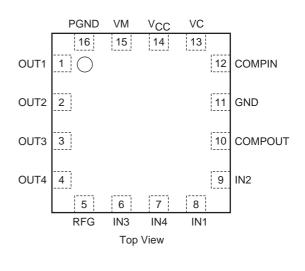
Package Dimensions

unit : mm (typ)

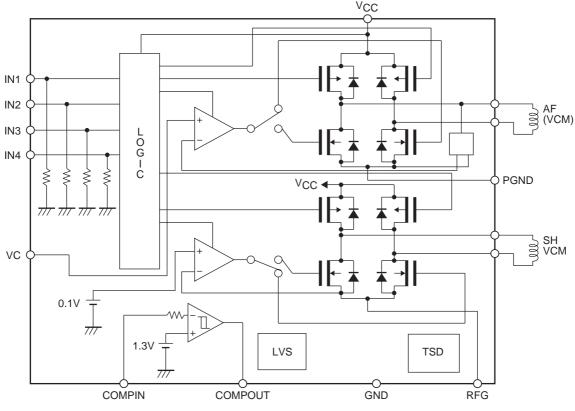


Pin Assignment

(VCT16)



Block Diagram



PCA01164

Constant-voltage calculation : $V_{OUT} = VC \times 2$ Example : When an V_{OUT} of 2V is required, VC must be 1V

Constant-current calculation : $I_{OUT} = 0.1 \div RF~$ Example : When an I_{OUT} of 100mA is required, RF must be 1Ω . Usage Notes

The constant current is set by the resource RF connected between RFG and ground according to the formula shown above.

Truth Table

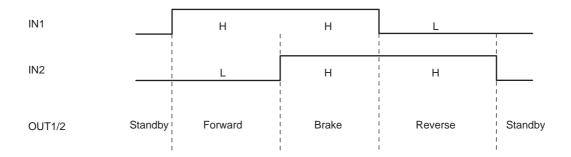
Input			Output			Mada					
IN1	IN2	IN3	IN4	OUT1	OUT2	OUT3	OUT4	Mode			
Low	Low	Low	Low				Off	Off			Standby mode
Low	High			au Lau	Low	ow High Off	Off	Channel 1, constant voltage, reverse			
High	Low			Low	High	Low	Oii		Channel 1, constant voltage, forward		
High	High			Low	Low			Channel 1, brake mode			
	1	Low	Low	Off		Off	Off	Standby mode			
Low		Low	High		0"	Off	Low	High	Channel 2, constant voltage, reverse		
Low Low	Low		Low		Oii	High	Low	Channel 2, constant voltage, forward			
	High High	High			Low	Low	Channel 2, brake mode				

Note: When off, a high-impedance state.

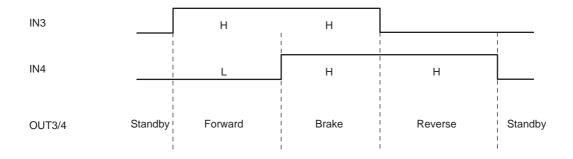
- Channel 1 functions as a constant voltage block (OUT1 and OUT2). Channel 2 functions as a constant-current block (OUT3 and OUT4).
- The IC goes to the standby state with a low-level input, and to the operating state with a high-level input.
- When the control inputs are both high, the IC switches to brake mode.

Timing Chart

(1) Constant voltage channel timing chart

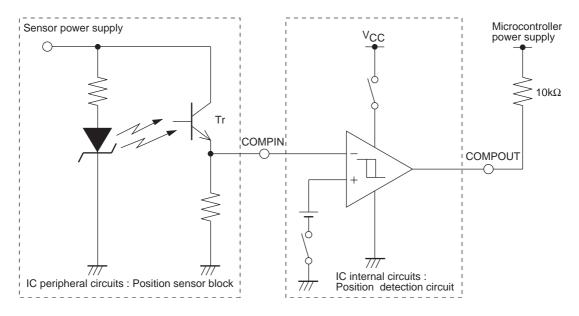


(2) Constant current channel timing chart

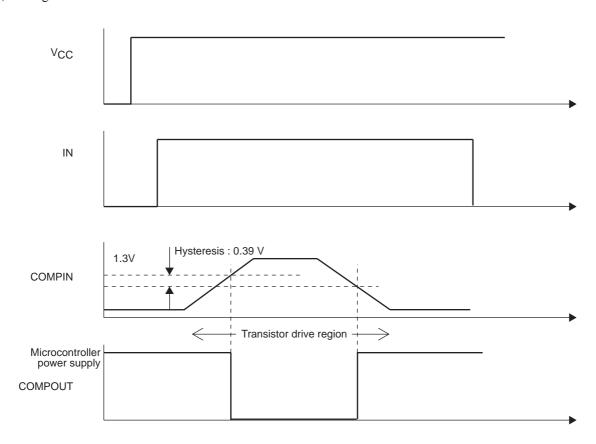


Photosensor Position Detection Application Circuit Example

(a) Application circuit



(b) Timing chart



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